

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	0	(Semiconductor memory device for performing refresh operation)	US-PGPUB	ADJ	ON	2006/01/30 10:02
S2	2720	(Semiconductor memory device).ti.	US-PGPUB	ADJ	ON	2006/01/25 12:31
S3	73	(Semiconductor memory device and refresh).ti.	US-PGPUB	ADJ	ON	2006/01/25 12:40
S4	601	(hynix).as.	US-PGPUB	ADJ	ON	2006/01/25 12:40
S5	5	S3 and S4	US-PGPUB	ADJ	ON	2006/01/25 12:31
S7	395	(Semiconductor memory device and refresh).ti.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/25 12:40
S8	22990	(hynix).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/25 12:40
S9	47	S7 and S8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/25 12:40
S10	11	("6,452,823" "6,412,044" "6,215,685" "6,223,248" "5,841,961" "5,226,009" "6,408,345" "5,513,335" "5,497,473" "5,469,555" "5,165,029").pn.	USPAT	OR	ON	2006/01/30 10:41
S11	329	711/106.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 10:43
S12	1	tag same (cell or block) same (row adj4 address) same (table or journal or log) and S11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 10:45
S13	1	tag same (cell or block) same (table or journal or log) and S11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 10:46

S14	10	tag same (cell or block) and S11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 10:52
S16	1866	711/105.ccls. or 711/106.ccls. or 711/108.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 10:54
S18	16	(711/105.ccls. or 711/106.ccls. or 711/108.ccls.) and ((refresh\$3 adj6 table) or (re-fresh\$3 adj6 table))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 11:09
S19	26425	365/???????.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 11:00
S21	28	S19 and ((refresh\$3 adj6 table) or (re-fresh\$3 adj6 table))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 11:01
S23	96	(711/105.ccls. or 711/106.ccls. or 711/108.ccls.) and (refresh\$3 or re-fresh\$3) and tag and (cell or block)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 11:09
S24	34	(711/105.ccls. or 711/106.ccls. or 711/108.ccls.) and (refresh\$3 or re-fresh\$3) and tag with (cell or block)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 11:11
S25	1	"20040221129"	US-PGPUB	ADJ	ON	2006/01/30 11:39
S26	90405	(unit near4 cell)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 12:18

S27	518	(unit near4 cell) and (unit near4 tag)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 12:18
S28	21	(unit near4 cell) and (unit near4 tag near4 block)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/01/30 12:57
S32	535	(content addressable memory).ti.	USPAT	ADJ	ON	2006/01/30 13:58